

## **isc Silicon NPN Power Transistor**

# BUY18S

#### DESCRIPTION

- Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 200V(MIN)
- Low Collector Saturation Voltage-
  - : V<sub>CE(sat)</sub>= 1.0V@ I<sub>C</sub>= 5A
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

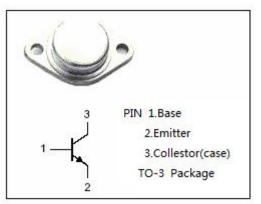
• Designed for use switching and general purpose applications.

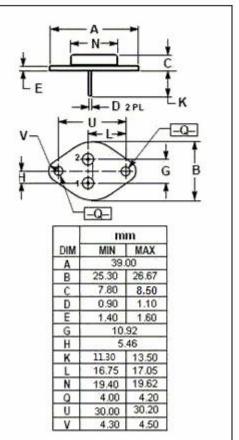
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	МАХ	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	400	V
V <sub>CEO</sub>	Collector-Emitter Voltage	200	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
Ic	Collector Current-Continuous	7	A
Pc	Collector Power Dissipation $@T_c < 75^{\circ}C$	50	W
Tj	Junction Temperature 150		°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT	
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.08	°C/W	







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## ELECTRICAL CHARACTERISTICS

### $T_{c}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	200			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	400			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1m A; I <sub>C</sub> = 0	6			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 0.5A			1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 0.5A			1.2	V
І <sub>сво</sub>	Collector Cutoff Current	V <sub>CB</sub> =400V; I <sub>E</sub> = 0			10	μA
hfe	DC Current Gain	Ic= 1A ; Vce= 5V	20			
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 5V		50		MHz

### **NOTICE:**

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